



#### **60V P-Channel Enhancement Mode MOSFET**

Voltage

-60 V

Current

-250mA

#### **Features**

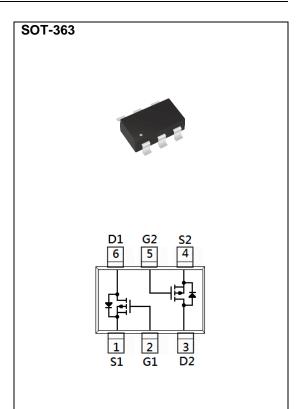
- RDS(ON), VGS@-10V, ID@-500mA<4Ω
- RDS(ON), VGS@-4.5V, ID@-200mA<6Ω
- RDS(ON), VGS@-2.5V, ID@-50mA<13Ω
- Advanced Trench Process Technology
- Specially Designed for Relay driver, Speed line drive, etc.
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-363 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0002 ounces, 0.006 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETE	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-60	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	-250	mA
Pulsed Drain Current <sup>(Note 1)</sup>		I <sub>DM</sub>	-1000	mA
Power Dissipation	T <sub>A</sub> =25°C	_	350	mW
	Derate above 25°C	P <sub>D</sub>	2.8	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>		Reja	357	°C/W





### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1.0	-1.5	-2.5	V		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-500mA	-	2.4	4	Ω		
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-200mA	-	2.65	6			
		V <sub>GS</sub> =-2.5V,I <sub>D</sub> =-50mA	-	4.5	13			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-48V,V <sub>GS</sub> =0V	-	-	-1	uA		
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 4)								
Total Gate Charge	Qg	\( \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	1.1	-	nC		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-25V, $I_{D}$ =-100mA, $V_{GS}$ =-4.5V	-	0.3	-			
Gate-Drain Charge	$Q_{gd}$	VGS=-4.5 V	-	0.2	-			
Input Capacitance	Ciss	), OFN N ON	-	51	-	pF		
Output Capacitance	Coss	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	15	-			
Reverse Transfer Capacitance	Crss	1=1.0IVII 1Z	-	2.2	-			
Turn-On Delay Time	td <sub>(on)</sub>	051/ 1 400 - 4	-	4.8	-			
Turn-On Rise Time	tr	$V_{DD}$ =-25V, $I_{D}$ =-100mA, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	19	-	ns		
Turn-Off Delay Time	td <sub>(off)</sub>		-	52	-			
Turn-Off Fall Time	tf	NG-022 ( *** / /	-	32	-			
Drain-Source Diode								
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	-250	mA		
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-500mA, V <sub>GS</sub> =0V	-	-0.95	-1.3	V		

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
- 4. Guaranteed by design, not subject to production testing





#### **TYPICAL CHARACTERISTIC CURVES**

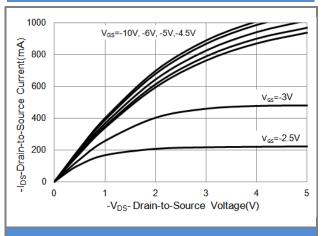
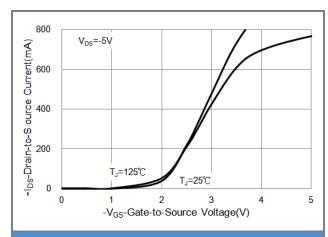


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

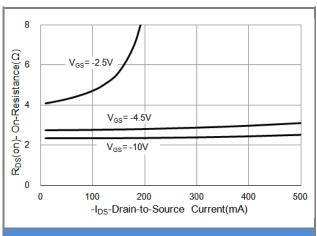


Fig.3 On-Resistance vs. Drain Current

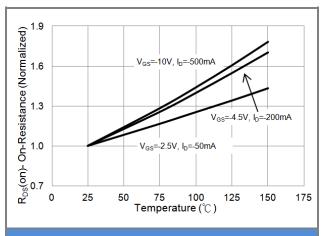
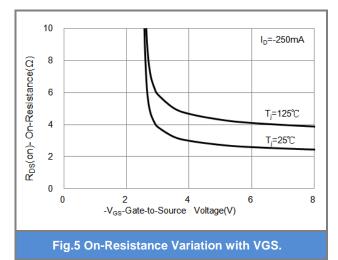
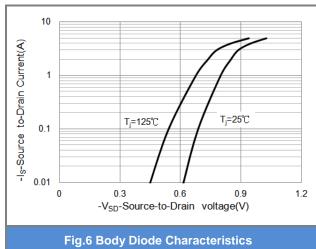


Fig.4 On-Resistance vs. Junction temperature









#### **TYPICAL CHARACTERISTIC CURVES**

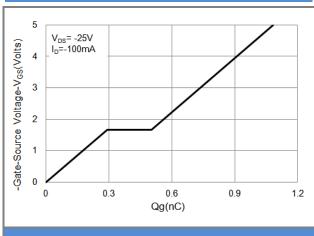


Fig.7 Gate-Charge Characteristics

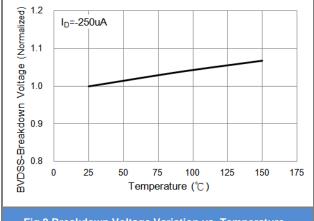


Fig.8 Breakdown Voltage Variation vs. Temperature

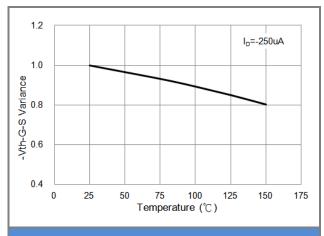


Fig.9 Threshold Voltage Variation with Temperature.

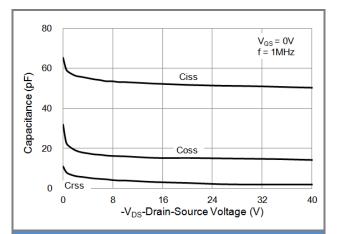


Fig.10 Capacitance vs. Drain-Source Voltage.

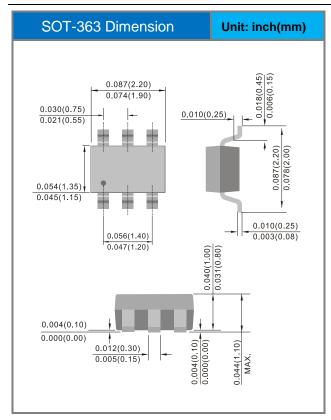


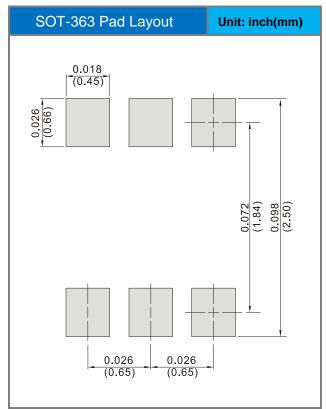


### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJT7839-AU_R1_000A1	SOT-363	3K pcs / 7" reel	T39	Halogen free RoHS compliant

## **Packaging Information & Mounting Pad Layout**









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